









	<h2 style="color: red;">DGD2103S8-13</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">DGD2103S8-13</a>
	<b>Hersteller / Marke:</b>	<a href="#">Diodes Incorporated</a>
	<b>Teil der Beschreibung:</b>	IC GATE DRVR HALF-BRIDGE 8SO
<b>Datenblätter:</b>	 <a href="#">DGD2103S8-13.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 12500 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	DGD2103S8-13
Hersteller	Diodes Incorporated
Beschreibung	IC GATE DRVR HALF-BRIDGE 8SO
Kategorie	<a href="#">Integrierte Schaltungen (ICs) &gt; PMIC-Gate-Treiber</a>
Teilstatus	12500 pcs Stock
Serie	-
Eingabetyp	Non-Inverting
Betriebstemperatur	-40°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Spannungsversorgung	10 V ~ 20 V
Ladestrom	Independent
Angetriebene Konfiguration	Half-Bridge
Anzahl der Treiber	2
Gate-Typ	IGBT, N-Channel MOSFET
Logikspannung - VIL, VIH	0.8V, 2.5V
Strom - Spitzenleistung (Quelle, Sink)	290mA, 600mA
Aufstieg / Fallzeit (Typ)	100ns, 35ns
High-Side-Spannung - Max (Bootstrap)	600V
Verpackung	Tape & Reel (TR)

DGD2103S8-13 ist neu im Original, Suche DGD2103S8-13 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DGD2103S8-13 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DGD2103S8-13: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>DGD21042S8-13</b> Diodes Incorporated IC GATE DVR HV 8SOIC</p>	 <p><b>DGD2101S8-13</b> Diodes Incorporated IC GATE DRVR HALF-BRIDGE 8SO</p>	 <p><b>DGD2103AS8-13</b> Diodes Incorporated IC GATE DRVR HALF-BRIDGE 8SO</p>	 <p><b>DGD2104MS8-13</b> Displaytech IC GATE DRVR HV SO8</p>
 <p><b>DGD21032S8-13</b> Diodes Incorporated IC GATE DVR HV 8SOIC</p>	 <p><b>DGD2104S8-13</b> Diodes Incorporated IC GATE DRVR HALF-BRIDGE 8SO</p>	 <p><b>DGD2104AS8-13</b> Diodes Incorporated IC GATE DRVR HALF-BRIDGE 8SO</p>	 <p><b>DGD2103MS8-13</b> Diodes Incorporated IC GATE DRVR HV SO8</p>

### heiße Teile

Mehr

<a href="#">12101U330FAT2A</a>	<a href="#">1812SC102KAT3A</a>	<a href="#">182NQ030R</a>	<a href="#">1N5819-T</a>	<a href="#">2MBI400U4B-120-50</a>
<a href="#">6MBI25S-120</a>	<a href="#">6MBP75RF120-01</a>	<a href="#">AOZ2262QI-18</a>	<a href="#">B37941K5102K60</a>	<a href="#">BA5810FP-E2</a>
<a href="#">BU9972GU</a>	<a href="#">BZD27-C30</a>	<a href="#">BZM55C7V5-TR3</a>	<a href="#">BZT52-C36</a>	<a href="#">C2012X7R2A473M125AA</a>
<a href="#">C5750X5R1C476M230KA</a>	<a href="#">CL10C681FB8NNNC</a>	<a href="#">DGD2104S8-13</a>	<a href="#">DGD2108S8-13</a>	<a href="#">DGD2113S16-13</a>
<a href="#">DGD2184S8-13</a>	<a href="#">FGA70N30TDTU</a>	<a href="#">FJZ733OTF</a>	<a href="#">GRM0335C1H7R7DD01D</a>	<a href="#">HO120-NP</a>
<a href="#">LB1965M-NMB-TLM3</a>	<a href="#">LD065C683KAB2A</a>	<a href="#">LM6181AIM8</a>	<a href="#">LT1764EQ-1.8#TRPBF</a>	<a href="#">MAC635-8</a>
<a href="#">MAX6831SVUT</a>	<a href="#">MCP1320T-46LE/OT</a>	<a href="#">MT48LC4M16A2P-75G</a>	<a href="#">MX29F040CTC-90G</a>	<a href="#">NB100ELT23LDR2</a>
<a href="#">PV23P503C01B00</a>	<a href="#">QSMT-UJHW-ZX3Z2</a>	<a href="#">R5F21256SNFP</a>	<a href="#">SC112CSK-3.8TR</a>	<a href="#">SC2603SKTRT</a>
<a href="#">SI1551DL-T1-E3</a>	<a href="#">SN74HCT373DWR</a>	<a href="#">SP310ACT</a>	<a href="#">SZMMBZ5223BLT1G</a>	<a href="#">TA75S558F</a>
<a href="#">TLC2932IPWLE</a>	<a href="#">TM130RZ-2H</a>	<a href="#">UV48-28-600G</a>	<a href="#">VI-234-03</a>	<a href="#">XC17256XPC</a>

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